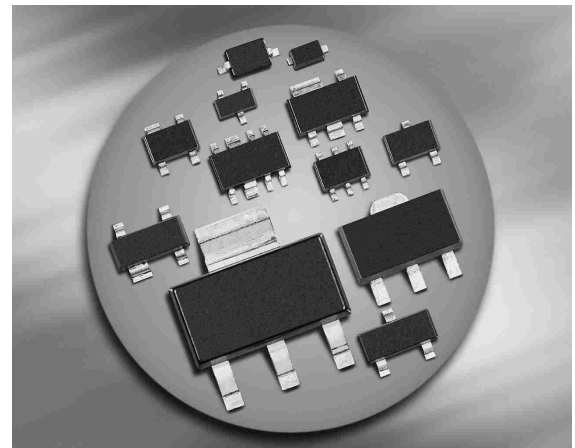
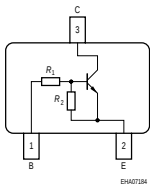


**NPN Silicon Digital Transistor**

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ( $R_1=4.7k\Omega$ ,  $R_2=4.7k\Omega$ )
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101


**BCR112**  
**BCR112W**


| Type    | Marking | Pin Configuration |     |     |   |   |   | Package |
|---------|---------|-------------------|-----|-----|---|---|---|---------|
| BCR112  | WFs     | 1=B               | 2=E | 3=C | - | - | - | SOT23   |
| BCR112W | WFs     | 1=B               | 2=E | 3=C | - | - | - | SOT323  |

**Maximum Ratings**

| Parameter                                                                                                 | Symbol       | Value       | Unit |
|-----------------------------------------------------------------------------------------------------------|--------------|-------------|------|
| Collector-emitter voltage                                                                                 | $V_{CEO}$    | 50          | V    |
| Collector-base voltage                                                                                    | $V_{CBO}$    | 50          |      |
| Input forward voltage                                                                                     | $V_{i(fwd)}$ | 30          |      |
| Input reverse voltage                                                                                     | $V_{i(rev)}$ | 10          |      |
| Collector current                                                                                         | $I_C$        | 100         | mA   |
| Total power dissipation-<br>BCR112, $T_S \leq 102^\circ\text{C}$<br>BCR112W, $T_S \leq 124^\circ\text{C}$ | $P_{tot}$    | 200<br>250  | mW   |
| Junction temperature                                                                                      | $T_j$        | 150         |      |
| Storage temperature                                                                                       | $T_{stg}$    | -65 ... 150 | °C   |

### Thermal Resistance

| Parameter                                | Symbol     | Value      | Unit |
|------------------------------------------|------------|------------|------|
| Junction - soldering point <sup>1)</sup> | $R_{thJS}$ |            | K/W  |
| BCR112                                   |            | $\leq 240$ |      |
| BCR112W                                  |            | $\leq 105$ |      |

<sup>1)</sup>For calculation of  $R_{thJA}$  please refer to Application Note AN077 (Thermal Resistance Calculation)

### Electrical Characteristics at $T_A = 25^\circ\text{C}$ , unless otherwise specified

| Parameter | Symbol | Values |      |      | Unit |
|-----------|--------|--------|------|------|------|
|           |        | min.   | typ. | max. |      |

#### DC Characteristics

|                                                                                                      |               |     |     |      |            |
|------------------------------------------------------------------------------------------------------|---------------|-----|-----|------|------------|
| Collector-emitter breakdown voltage<br>$I_C = 100 \mu\text{A}$ , $I_B = 0$                           | $V_{(BR)CEO}$ | 50  | -   | -    | V          |
| Collector-base breakdown voltage<br>$I_C = 10 \mu\text{A}$ , $I_E = 0$                               | $V_{(BR)CBO}$ | 50  | -   | -    |            |
| Collector-base cutoff current<br>$V_{CB} = 40 \text{ V}$ , $I_E = 0$                                 | $I_{CBO}$     | -   | -   | 100  | nA         |
| Emitter-base cutoff current<br>$V_{EB} = 10 \text{ V}$ , $I_C = 0$                                   | $I_{EBO}$     | -   | -   | 1.61 | mA         |
| DC current gain <sup>1)</sup><br>$I_C = 5 \text{ mA}$ , $V_{CE} = 5 \text{ V}$                       | $h_{FE}$      | 20  | -   | -    | -          |
| Collector-emitter saturation voltage <sup>1)</sup><br>$I_C = 10 \text{ mA}$ , $I_B = 0.5 \text{ mA}$ | $V_{CEsat}$   | -   | -   | 0.3  | V          |
| Input off voltage<br>$I_C = 100 \mu\text{A}$ , $V_{CE} = 5 \text{ V}$                                | $V_{i(off)}$  | 0.8 | -   | 1.5  |            |
| Input on voltage<br>$I_C = 2 \text{ mA}$ , $V_{CE} = 0.3 \text{ V}$                                  | $V_{i(on)}$   | 1   | -   | 2.5  |            |
| Input resistor                                                                                       | $R_1$         | 3.2 | 4.7 | 6.2  | k $\Omega$ |
| Resistor ratio                                                                                       | $R_1/R_2$     | 0.9 | 1   | 1.1  | -          |

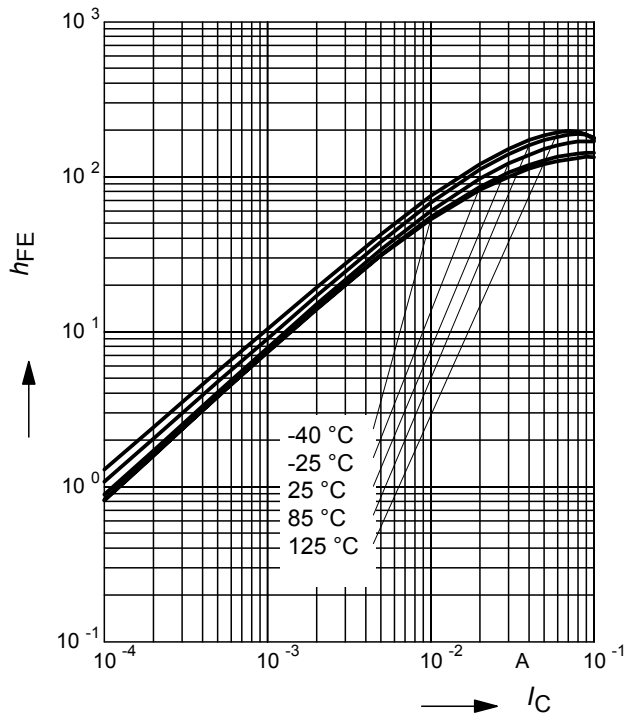
#### AC Characteristics

|                                                                                                |          |   |     |   |     |
|------------------------------------------------------------------------------------------------|----------|---|-----|---|-----|
| Transition frequency<br>$I_C = 10 \text{ mA}$ , $V_{CE} = 5 \text{ V}$ , $f = 100 \text{ MHz}$ | $f_T$    | - | 140 | - | MHz |
| Collector-base capacitance<br>$V_{CB} = 10 \text{ V}$ , $f = 1 \text{ MHz}$                    | $C_{cb}$ | - | 3   | - | pF  |

<sup>1)</sup>Pulse test:  $t < 300 \mu\text{s}$ ;  $D < 2\%$

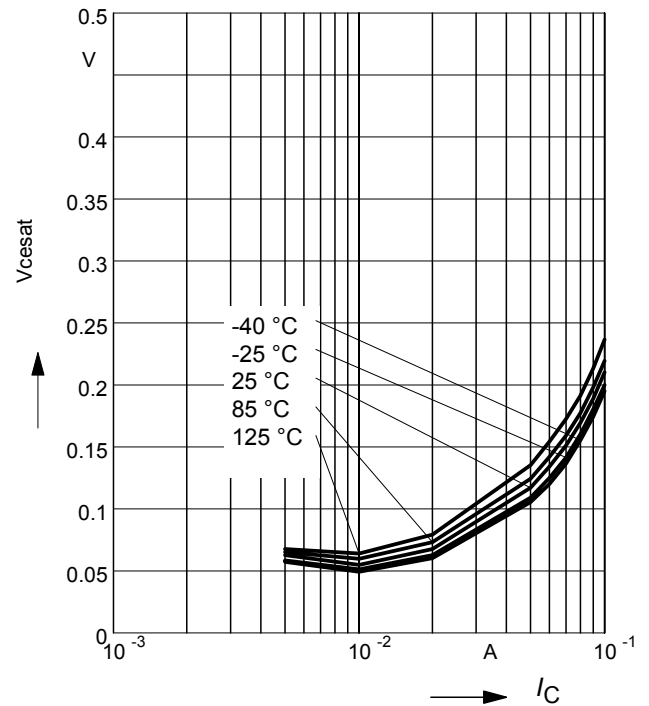
### DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5 \text{ V}$  (common emitter configuration)



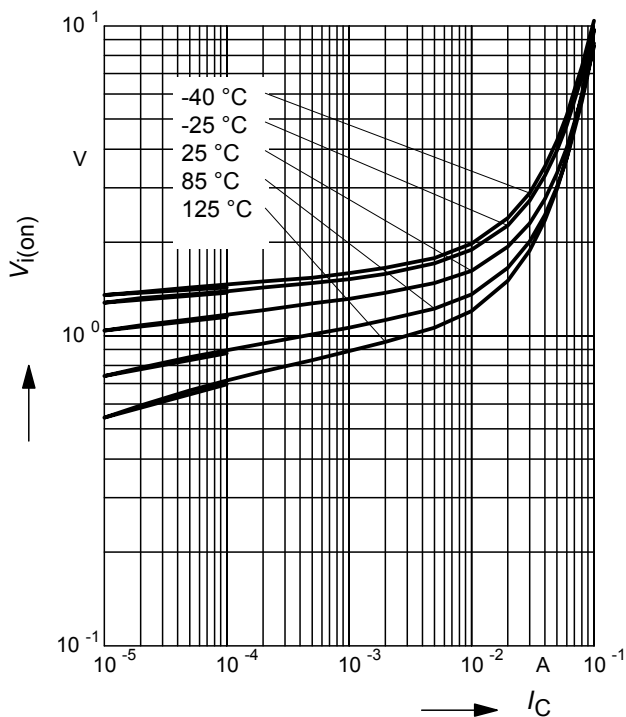
### Collector-emitter saturation voltage

$V_{CEsat} = f(I_C)$ ,  $I_C/I_B = 20$



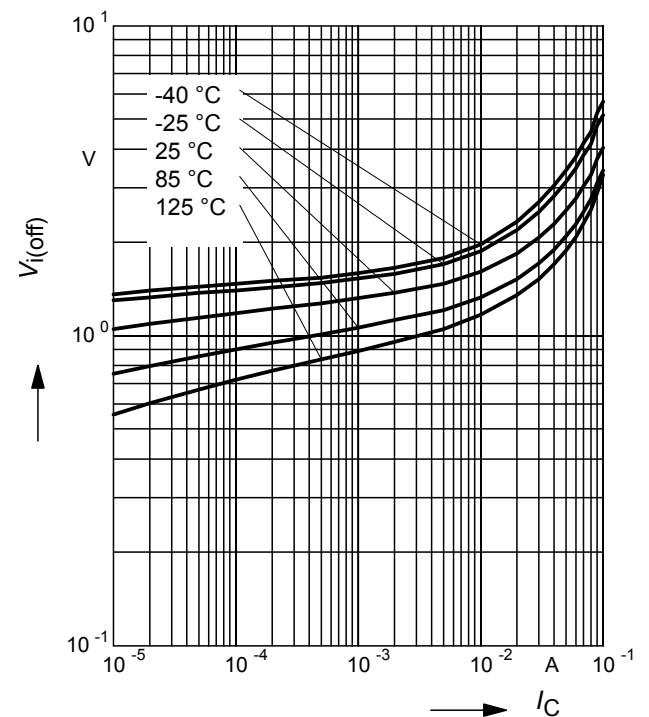
### Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3 \text{ V}$  (common emitter configuration)



### Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5 \text{ V}$  (common emitter configuration)



**Total power dissipation  $P_{\text{tot}} = f(T_S)$**

BCR112



**Total power dissipation  $P_{\text{tot}} = f(T_S)$**

BCR112W



**Permissible Pulse Load  $R_{\text{thJS}} = f(t_p)$**

BCR112



**Permissible Pulse Load**

$P_{\text{totmax}}/P_{\text{totDC}} = f(t_p)$

BCR112



# Permissible Puls Load $R_{thJS} = f(t_p)$

BCR112W



# Permissible Pulse Load

$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR112W



## Package Outline

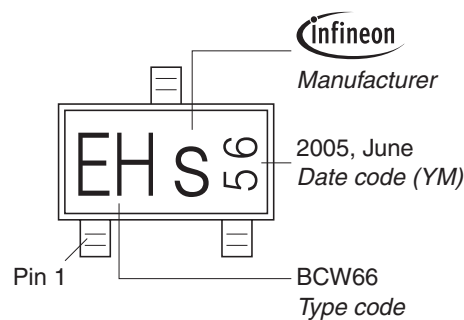


1) Lead width can be 0.6 max. in dambar area

## Foot Print



## Marking Layout (Example)

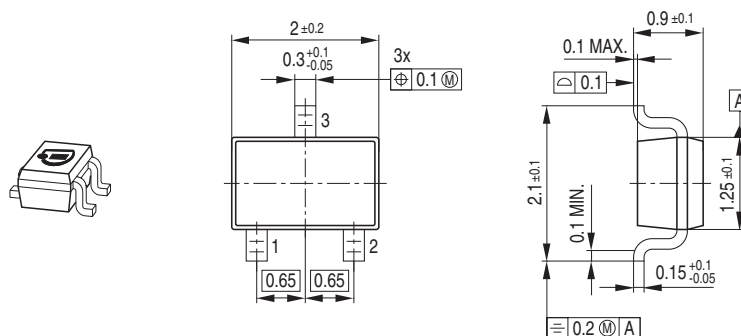


## Standard Packing

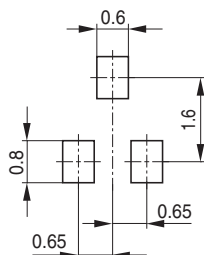
Reel ø180 mm = 3.000 Pieces/Reel  
Reel ø330 mm = 10.000 Pieces/Reel



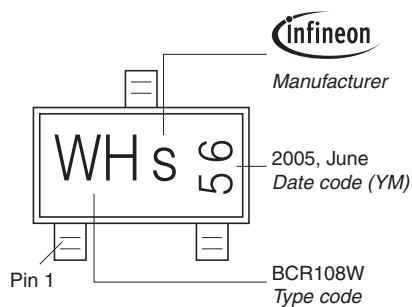
## Package Outline



## Foot Print

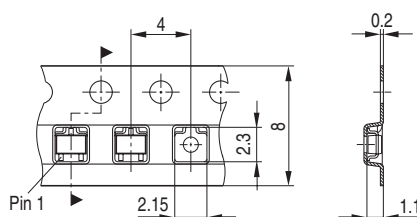


## Marking Layout (Example)



## Standard Packing

Reel  $\varnothing 180 \text{ mm}$  = 3.000 Pieces/Reel  
 Reel  $\varnothing 330 \text{ mm}$  = 10.000 Pieces/Reel



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